

10V Drive Nch MOSFET

R5005CNJ

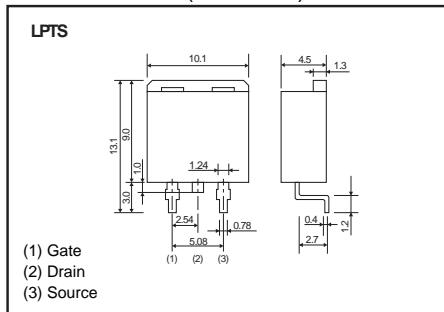
● Structure

Silicon N-channel MOSFET

● Features

- 1) Low on-resistance.
- 2) High-speed switching.
- 3) Wide range of SOA.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.

● Dimensions (Unit : mm)



● Application

Switching

● Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	1000
R5005CNJ	O	

● Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Drain-source voltage	V_{DSS}	500	V
Gate-source voltage	V_{GSS}	± 30	V
Drain current	Continuous	I_D *3	A
	Pulsed	I_{DP} *1	A
Source current (Body Diode)	Continuous	I_S *3	A
	Pulsed	I_{SP} *1	A
Avalanche current	I_{AS} *2	2.5	A
Avalanche energy	E_{AS} *2	1.6	mJ
Power dissipation	P_D *4	40	W
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Range of storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

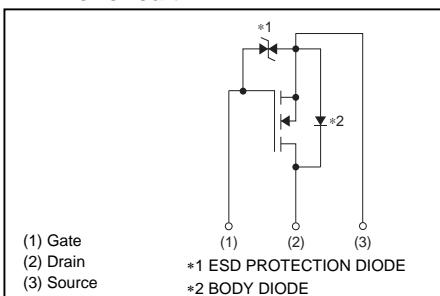
*1 $P_w \leq 10 \mu\text{s}$, Duty cycle $\leq 1\%$

*2 $L = 500 \mu\text{H}$, $V_{DD} = 50\text{V}$, $R_G = 25\Omega$, $T_{ch} = 25^\circ\text{C}$

*3 Limited only by maximum temperature allowed.

*4 $T_C = 25^\circ\text{C}$

● Inner circuit



● Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to Case	$R_{th(ch-c)}$	3.125	$^\circ\text{C} / \text{W}$

● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	-	-	±10	μA	V _{GS} =±25V, V _{DS} =0V
Drain-source breakdown voltage	V _{(BR)DSS}	500	-	-	V	I _D =1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	-	-	100	μA	V _{DS} =500V, V _{GS} =0V
Gate threshold voltage	V _{GS (th)}	2.5	-	4.5	V	V _{DS} =10V, I _D =1mA
Static drain-source on-state resistance	R _{DS (on)*}	-	1.3	1.6	Ω	I _D =2.5A, V _{GS} =10V
Forward transfer admittance	Y _{fs} *	1.5	2.7	-	S	V _{DS} =10V, I _D =2.5A
Input capacitance	C _{iss}	-	320	-	pF	V _{DS} =25V
Output capacitance	C _{oss}	-	180	-	pF	V _{GS} =0V
Reverse transfer capacitance	C _{rss}	-	15	-	pF	f=1MHz
Turn-on delay time	t _{d(on)*}	-	20	-	ns	V _{DD} =250V, I _D =2.5A
Rise time	t _r *	-	25	-	ns	V _{GS} =10V
Turn-off delay time	t _{d(off)*}	-	40	-	ns	R _L =100Ω
Fall time	t _f *	-	20	-	ns	R _G =10Ω
Total gate charge	Q _g *	-	10.8	-	nC	V _{DD} =250V
Gate-source charge	Q _{gs} *	-	3.2	-	nC	I _D =5.0A
Gate-drain charge	Q _{gd} *	-	4.4	-	nC	V _{GS} =10V

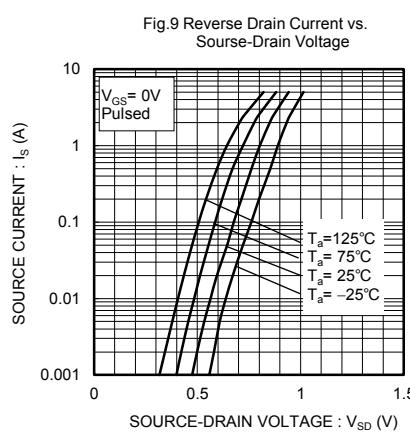
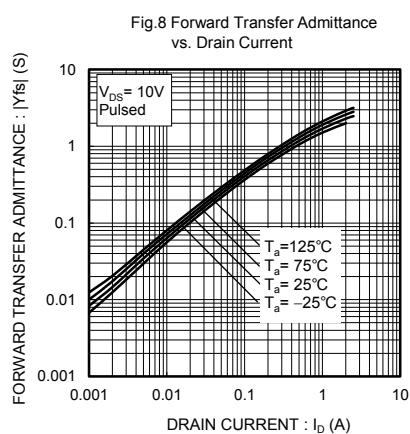
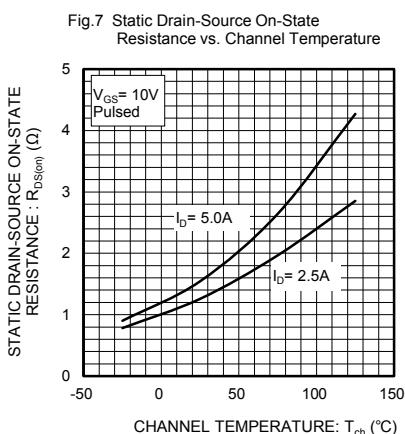
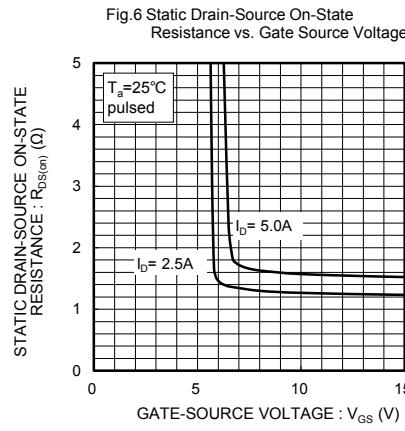
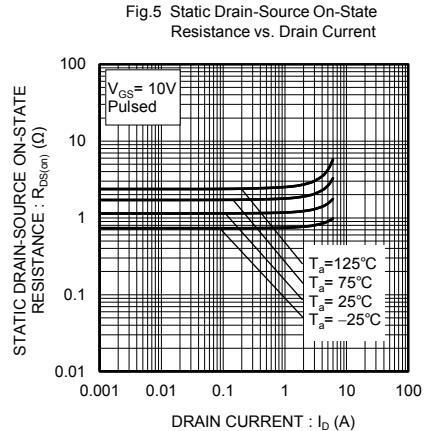
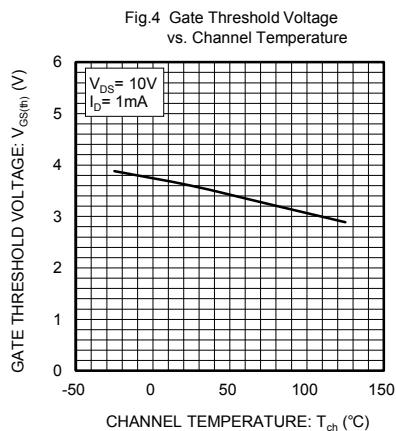
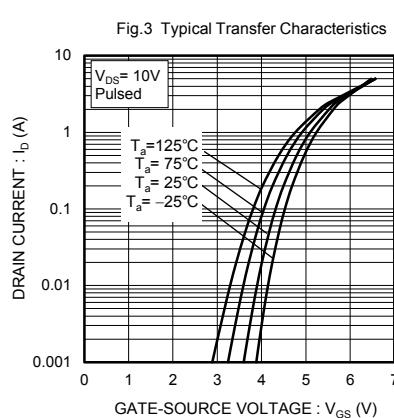
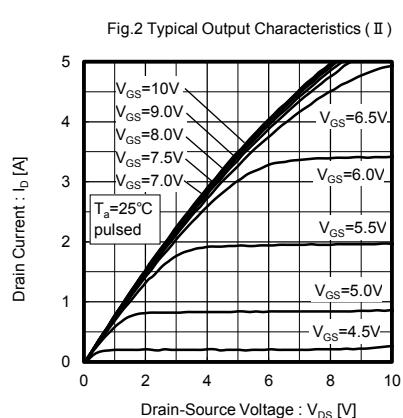
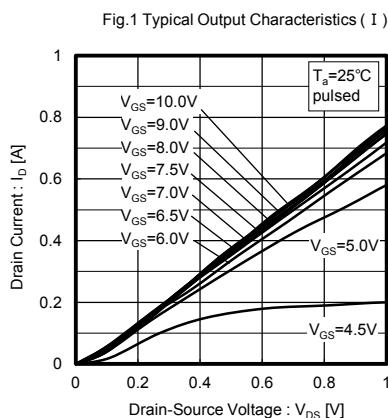
*Pulsed

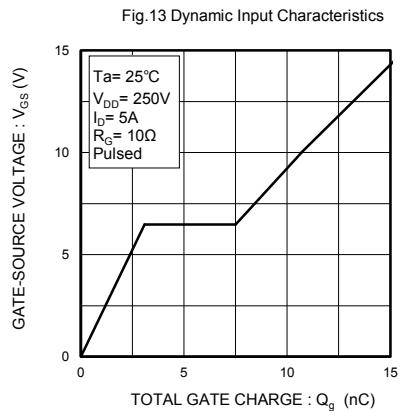
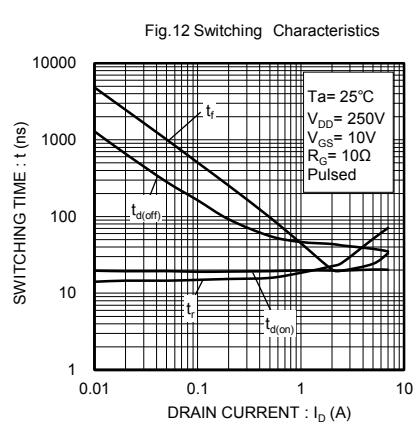
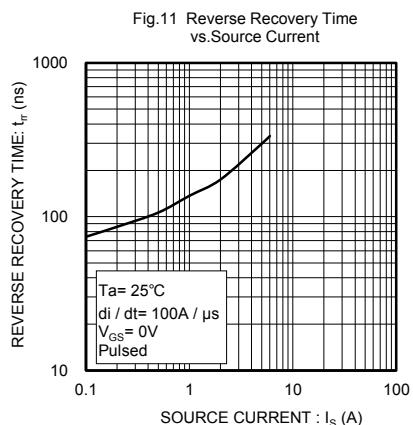
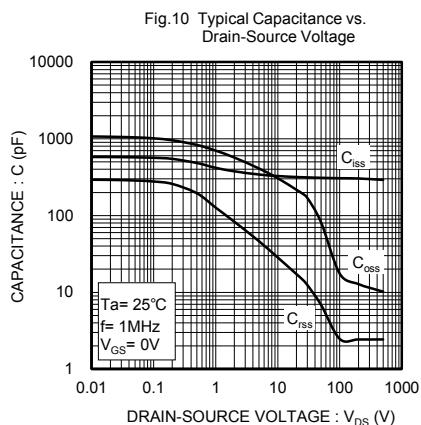
● Body diode characteristics (Source-Drain)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	V _{SD} *	-	-	1.5	V	I _S =5.0A, V _{GS} =0V

*Pulsed

● Electrical characteristic curves





● Measurement circuits

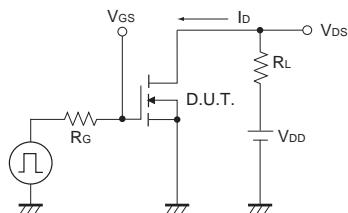


Fig.1-1 Switching Time Measurement Circuit

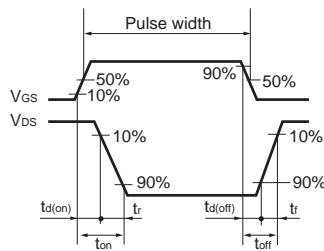


Fig.1-2 Switching Waveforms

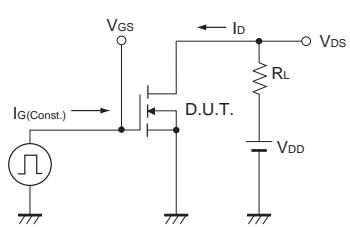


Fig.2-1 Gate Charge Measurement Circuit

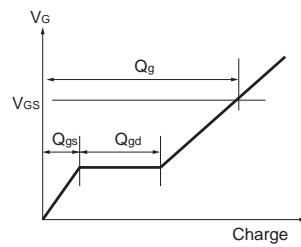


Fig.2-2 Gate Charge Waveform

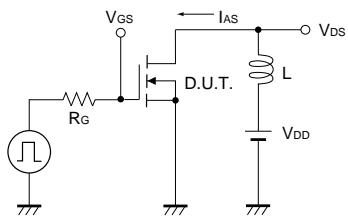


Fig.3-1 Avalanche Measurement Circuit

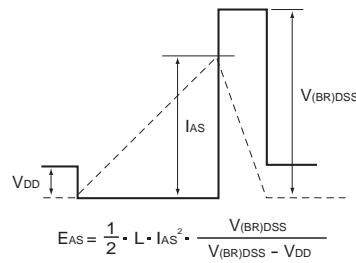


Fig.3-2 Avalanche Waveform

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